

December 11, 2014

## Product Specifications of the RMLV0816B and RMLV0808B Series of SRAM (8 Mbit, 110 nm Process)

Part Number	Word Organization	Package	Supply Voltage	Access Time	Pin Type	Standby Current	Sample Pricing	Availability						
RMLV0816 BGSB-4S2	x16	TSOP II (44)	2.7 V– 3.6 V	45 ns	CS1	Up to 25°C: 2 μA (max.) Up to 40°C: 4 μA (max.) Up to 70°C: 7 μA (max.) Up to 85°C: 10 μA (max.)	US\$11	April 2015						
			2.4 V– 2.7 V	55 ns										
RMLV0816 BGSA-4S2		TSOP I (48)	2.7 V– 3.6 V	45 ns	CS2			US\$11	US\$11	April 2015				
			2.4 V– 2.7 V	55 ns										
RMLV0816 BGBG-4S2		FBGA (48)	2.7 V– 3.6 V	45 ns	CS2					US\$11	US\$11	December 2014		
			2.4 V– 2.7 V	55 ns										
RMLV0816 BGSD-4S2		mTSOP II (52)	2.7 V– 3.6 V	45 ns	CS2							US\$11	US\$11	April 2015
			2.4 V– 2.7 V	55 ns										
RMLV0808 BGSB-4S2	x8	TSOP II (44)	2.7 V– 3.6 V	45 ns	CS2	US\$11	US\$11							April 2015
			2.4 V– 2.7 V	55 ns										

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